

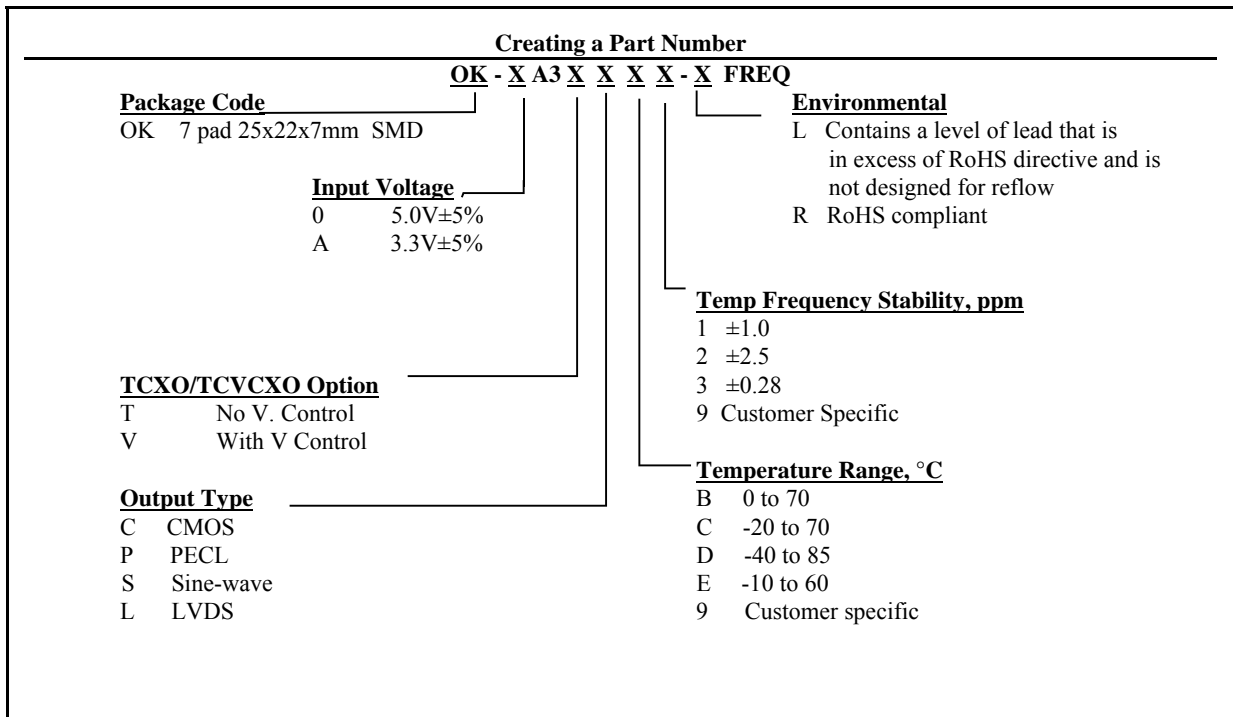
**HF/UHF SMD TCVCXO
OK-XA3XXXX-X Series**

Description

The **OK-XA3XXXX Series** of SMD temperature compensated, voltage controlled crystal oscillators (TCVCXO) provides High and Ultra High Frequency with excellent temperature stability, extremely low phase noise and jitter with variety of different output types in a small surface mount FR4 based package.

Applications and Features

- Ultra High Frequency - up to 1GHz
- Small, Low Profile SMD Package
- Very Low Phase Jitter and Phase Noise
- Excellent Frequency Stability
- CMOS, Sine-wave, Differential PECL or LVDS outputs available
- Stratum 3 available
- COTS/Dual use



OK-XA3XXXX-X Series Continued
HF/UHF SMD TCVCXO

Rev. L

Absolute Maximum Ratings

| Parameter | Sym | Condition | Min | Typ | Max | Unit | Note |
|--------------------------|-----|-----------|------|-----|-----|------|------|
| Input Break Down Voltage | Vcc | | -0.5 | | 5.5 | V | |
| Storage Temperature | Ts | | -40 | | 105 | °C | |
| Control Voltage | Vc | | -1 | | 9 | V | |

Electrical Parameters (1)

| Parameter | Sym | Conditions | MIN | TYP | MAX | Unit | Note |
|-----------------------|-------|------------------------------------|---|----------------------------|-----------------------|---------------------------------|---|
| Frequency Range | F | CMOS Sine-wave PECL, LVDS | 30 30 30 | | 200 1,000 1,000 | MHz | |
| Input Voltage | Vcc | Code 0 Code A | 4.75 3.135 | 5.0 3.3 | 5.25 3.465 | V | |
| Input current | Icc | CMOS, Sine PECL, Sine, LVDS | | | 30 100 | mA | @100MHz, 3.3V @622MHz, 3.3V |
| Frequency Stability | ΔF/F | Overall, available | | | ±4.6 | | 20 years |
| Frequency Stability | ΔF/F | vs Temperature vs Vcc Aging | | ±0.5 ±0.1 ±1 ±3.5 | ±1 | ppm ppm/V ppm/year ppm | See Chart First Year 10 years |
| Calibration | ΔF/F | As shipped, 25°C | | ±0.5 | ±1 | ppm | |
| Load | | CMOS Sinewave PECL LVDS | 15pf/10KOhmOhm Internally AC-coupled 50 Ohm 50 Ohm to Vcc-2V or Thevenin equivalent 100 Ohm between the outputs, receiving end | | | | |
| Duty Cycle | | At 50 % | 45/55 | 50/50 | 55/45 | % | CMOS, PECL, LVDS |
| Rise/Fall Time | Tr/Tf | 20 to 80% | | 3 0.35 | | ns | CMOS PECL, LVDS |
| Logic "1" level | Voh | CMOS | 0.9Vcc | | | V | |
| Logic "0" level | Vol | CMOS | | | 0.1Vcc | V | |
| Logic "1" level | Voh | PECL | Vcc-0.96 | | Vcc-0.81 | V | 100K available |
| Logic "0" level | Vol | PECL | Vcc-1.85 | | Vcc-1.65 | V | 100K available |
| Output Levels LVDS | Vod | Differential amplitude | 247 | 330 | 454 | mV | |
| | | Amplitude error | | | 50 | mV | |
| | Vof | Offset Voltage | 1.125 | 1.25 | 1.375 | V | |
| | | Offset Voltage error | | | 50 | mV | |
| Output power | P | Sinewave Into 50 Ohm <=/=400MHz | 0 4 | 3 7 | | dBm | 3.3V 5.0V |
| | | Sinewave Into 50 ohm >400MHz | -5 0 | 0 5 | 5 | | 3.3V 5.0V |
| | | | | | | | |
| | | | | | | | |
| Start up Time | Ts | | | 2 | 10 | ms | |
| Phase jitter | | 1 sigma | | 0.4 0.2 | 1 0.4 | ps | 100Hz to 20MHz 12kHz to 20MHz |
| Sub-harmonics | | PECL, LVDS, Sine CMOS, Sine | | -45 | -40 none | dBc | F>250MHz F<250MHz |
| Spurious | | | | | -60 | dBc | |
| Harmonics | | Sine-wave | | -30 | -25 | dBc | |
| SSB Phase Noise | | @10 Hz | | -80 | | dBc/Hz | @ 100 MHz |
| | | @100 Hz | | -110 | | | |
| | | @1 KHz | | -140 | | | |
| | | @10KHz | | -155 | | | |
| | | @100KHz | | -160 | | | |
| SSB Phase Noise | | @10 Hz | | -60/-60 | | dBc/Hz | @ 622 Mhz; PECL, LVDS/Sine |
| | | @100 Hz | | -90/-90 | | | |
| | | @1 KHz | | -120/-120 | | | |
| | | @10KHz | | -140/-145 | | | |
| | | @100KHz | | -145/-150 | | | |
| Input Impedance | | | > 10 K Ohm | | | | |
| Control Voltage | Vc | | 0 | | 3.3 | V | for 3.3V supply |
| | | | 0 | | 5.0 | V | for 5.0V supply |
| Modulation Bandwidth | MB | | 2Hz | | | | Contact Factory for wider MB |
| Deviation | | Vc=0V to 3.3V, 25°C | ±5 | ±7 | | ppm | |

Note 1. All parameters, unless otherwise specified, are at nominal conditions, ie: T=25°C, Nominal Vcc & Nominal Load.



**FREQUENCY
CONTROLS, INC.**

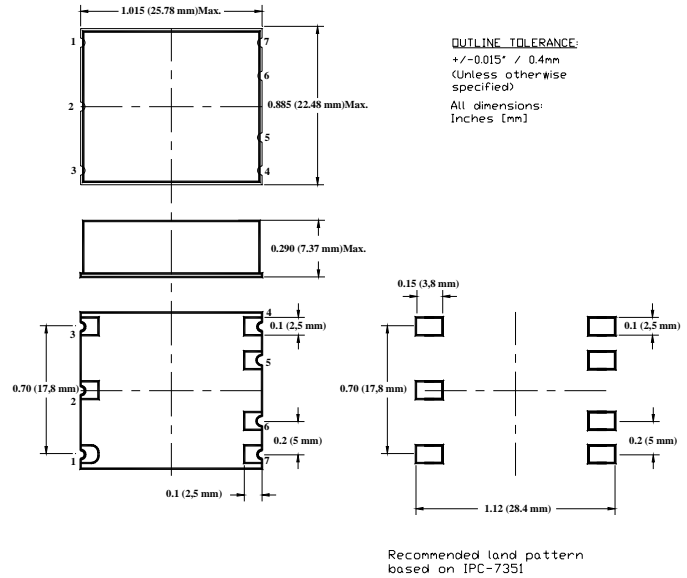
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OK-XA3XXXX-X Series Continued HF/UHF SMD TCVCXO

Electrical Connection

| Pin | Connection |
|-----|-------------------------|
| 1 | Voltage Control |
| 2 | NC |
| 3 | V _{CC} |
| 4 | Output, CMOS or Sine |
| 5 | Output, PECL/LVDS |
| 6 | Comp. Output, PECL/LVDS |
| 7 | Gnd |

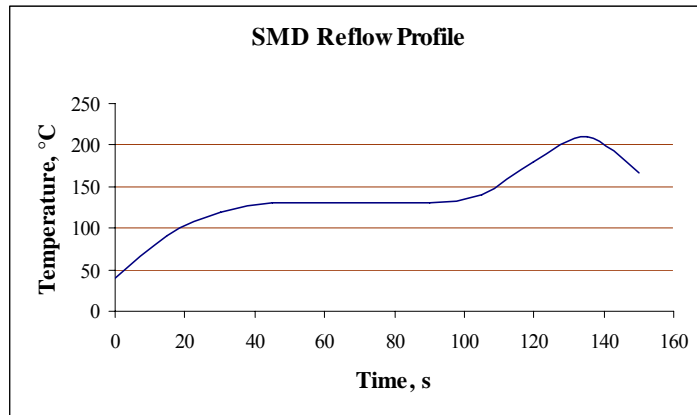
Note: For frequency stability over temperature ± 1 ppm and tighter, the package height may be 10mm or 12.5mm.



Environmental and Mechanical Characteristics

| | |
|------------------------------|--|
| Operating temp. range | 0°C to 70°C, -40°C to 85°C, see chart page 1 |
| Mechanical Shock | Per MIL-STD-202, Method 213, Cond. E |
| Thermal Shock | Per MIL-STD-883, Method 1011, Cond. A |
| Vibration | Per MIL-STD-883, Method 2007, Cond. A |
| Hermetic Seal | Leak rate less than 1×10^{-8} atm.cc/s of helium (crystal only) |
| Soldering conditions | See MAX reflow profile below; The device may be reflowed once. Reflowing upside down is not allowed. NO CLEAN assembly is recommended. |

Maximum Reflow Profile



The device may be reflowed once. Reflowing upside down is not allowed. NO CLEAN assembly is recommended.

